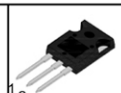
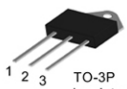
SB7560S 75A SCRs

FEATURES

- High thermal cycling performance
- High voltage capacity
- Very high current surge capability

Parameters Summary





●APPLICATIONS

- Line rectifying 50/60 Hz
- Softstart AC motor control
- DC Motor control
- Power converter
- AC power control
- Lighting and temperature control

SMD Device Halogen Free

Pb-free

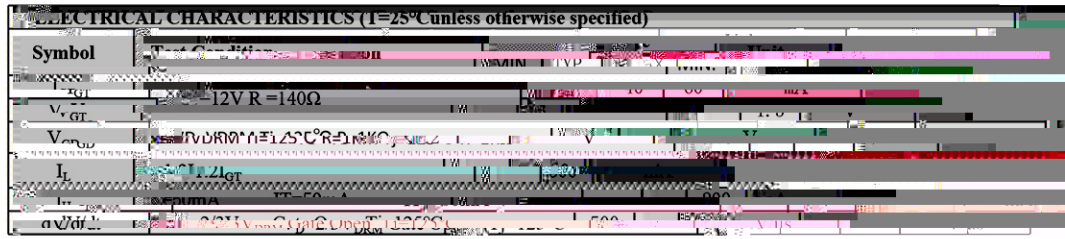
RoHS COMPLIANT

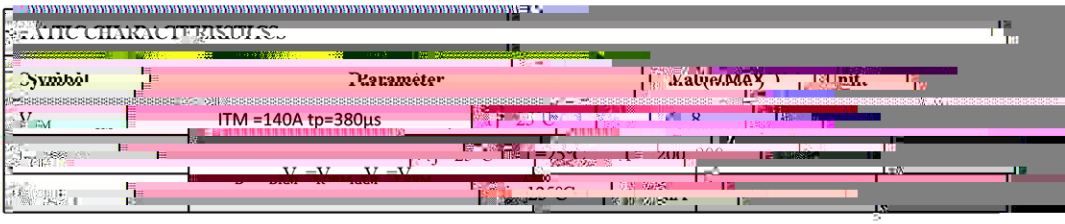
ABSOLUTE MAXIMUM RATINGS

Parameter	Symbol	Value	Unit
Storage junction temperature range	Tstg	-40 ~150	℃
Operating junction temperature range	T_j	-40~125	℃
Repetitive peak off-state voltage (T =25℃)	V_{DRM}	1200/1600	V
Repetitive peak reverse voltage (T =25℃)	V_{RRM}	1200/1600	V
Non repetitive surge peak Off-state voltage	V_{DSM}	V_{DRM}+100	V
Non repetitive peak reverse voltage	V_{RSM}	V_{RRM}+100	V
RMS on-state current (T =100℃)	$I_{T(RMS)}$	75	A
Non repetitive surge peak on-state current	I_{TSM}	700	A
I^2t value for fusing (tp=10ms)	I^2t	2450	A^2s
Critical rate of rise of on-state curren t(I =2×IGT, tr ≤ 100 ns)	di/dt	150	A/μS
Peak gate current	I_{GM}	5	A
Average gate power dissipation	$P_{G(AV)}$	2	W

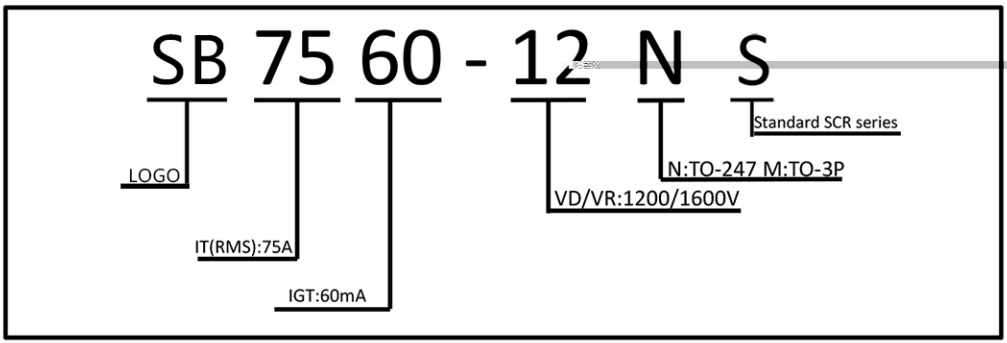
Thermal Resistances

Symbol	Parameter		Value	Unit
Rth(j-c)	Junction to case (DC)	TO-3P	0. 60	℃/W
		TO-247	0. 55	

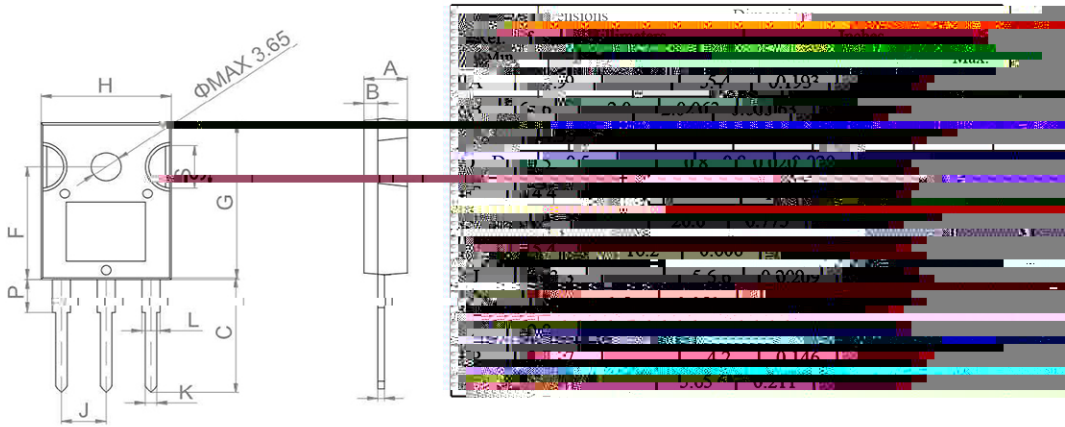




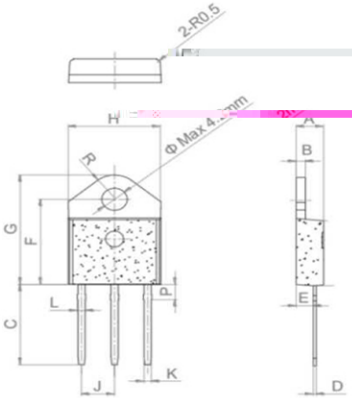
Ordering Information Scheme



TO-247 Package Mechanical Data



TO-3P Package Mechanical Data



Ref.	Dimensions					
	Millimeters			Inches		
	Min.	Typ.	Max.	Min.	Typ.	Max.
A	4.40		4.60	0.173		0.181
B	1.40		1.60	0.055		0.062
C	15.48		15.88	0.609		0.625
D	0.50		0.70	0.019		0.027
E	2.70		2.90	0.106		0.114
F	15.92		16.32	0.626		0.642
G	20.27		20.67	0.798		0.813
H	15.15		15.35	0.590		0.604
J		5.45			0.214	0.216
K	1.10		1.30	0.043		0.051
L	1.15		1.35	0.045		0.053
P	2.68		3.08	0.105		0.121
R		4.20			0.165	

FIG.1 Maximum power dissipation versus on-state current

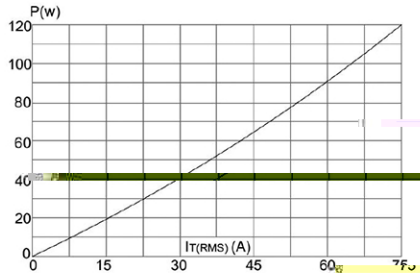


FIG.2: on-state current versus case temperature

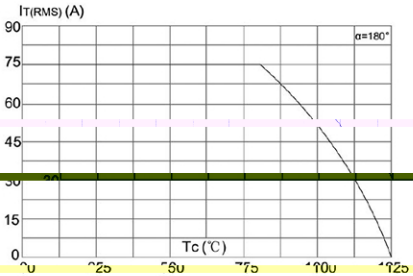


FIG.3: Surge peak on-state current versus number of cycles

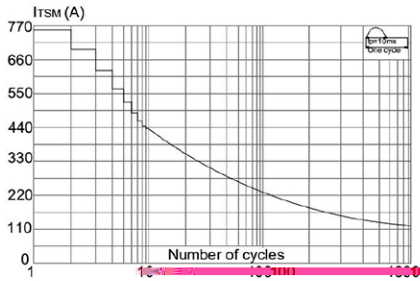


FIG.4: On-state characteristics (maximum values)

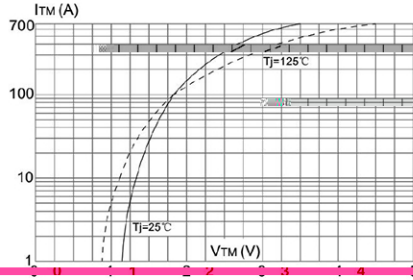


FIG.5: Non-repetitive surge peak on-state currentfor a sinusoidal pulse with width tp<10ms, and corresponding value of I2 t (dI/dt < 50A/μs)

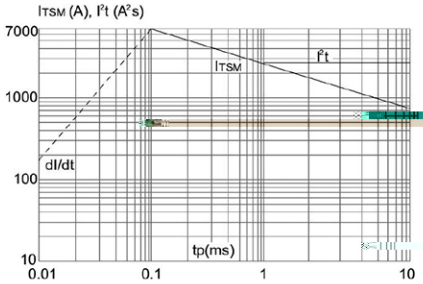


FIG.6: Relative variations of gate trigger current, holding current and latching current versus junction temperature